



双相位, D-CAP+™, Eco-mode™ 降压控制器,此控制器具有 8 位数模 转换器 (DAC)

查询样品: TPS53624

特性

- 可选双相位或单相位
- 最小外部部件数量
- 8位 DAC 支持广泛应用
- 轻负载与重负载下已优化的效率
- 已获专利的输出过冲减少 (OSR) 减少了输出电容
- 精确的、可调电压配置
- 可选 200, 300, 400 和 500kHz 频率
- 正在申请专利的 自动平衡相位均衡
- 可选 8 级电流限制
- 3V 至 28V 转换电压范围
- 具有集成型升压二极管的快速金属氧化物半导体场效应晶体管 (MOSFET) 驱动器
- 集成过压保护 (OVP)
- 小型 6 x 6, 40 引脚,四方扁平无引线封装 (QFN) PowerPAD™ 封装

应用范围

高电流、低压特定用途集成电路 (ASIC) 或微处理器内核稳压器

说明

TPS53624 是一款具有集成栅极驱动器的双相位降压 控制器。 PCNT 引脚在双相位或单相位模式中启用运 行来根据负载要求优化效率。 先进的控制特性包括诸 如 D-CAP+™ 架构和 OSR 等使用低输出电容提供快 速瞬态响应的特性。 DAC 支持快速电压识别 (VID OTF) 来优化传送给处于运行状态的系统的输出电压以 减少静态功耗。 TPS53624 的自动跳跃特性优化了单 相位运行中的轻负载效率。 系统管理特性包括可调热 监控输入和输出 (THRM, THAL), 输出电流监控 (IMON),以及互补电源正常信号(PG和 PGD)。提 供了输出电压转换率和电压配置的可调节控制。 此 外, TPS53624 包括 2 个高电流场效应晶体管 (FET) 栅极驱动器来以极高的速度和低开关损耗驱动高侧和低 侧 N 通道 FET。 所有逻辑输入和输出引脚具有灵活的 LV 输入和输出阀值,此阀值能够在 1V 至 3.6V 的逻 辑电压范围内启用接口。

TPS53624 采用节省空间、耐热增强型、符合 RoHS 环保标准的 40 引脚 QFN 封装,额定运行稳定介于 - 10°C 至 105°C 之间。

订购信息(1)

T _A	封装	器件 编号	引脚	输出 电源	最少 订购数量
-10°C 至 105°C	御料田子白亚科荘 (OFN)	TPS53624RHAT	40	卷带包装	250
	塑料四方扁平封装 (QFN)	TPS53624RHAR			2500

(1) 要获得最新的封装和订购信息,请参见本文档末尾的封装信息,或者浏览德州仪器 (TI) 的网站www.ti.com。

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature range (unless otherwise noted, all voltages are with respect to GND.) (1)

_		VAI	VALUE		
		MIN	MAX	UNIT	
	VBST1, VBST2	-0.3	36		
Input voltage range ⁽²⁾	VBST1to LL1. VBST2 to LL2	-0.3	6		
	CSP1, CSN1, CSP2, CSN2, MODE, OSRSEL, PCNT, SLEW, THRM, TRIPSEL, TONSEL, V5FILT, V5IN, VID0, VID1, VID2, VID3, VID4, VID5, VID6, VID7, VFB, EN, THAL	-0.3	6	V	
	LL1, LL2	– 5	30		
	DRVH1, DRVH2	– 5	36	V	
Output voltage range ⁽²⁾	DRVH1, DRVH2 to LL1 or LL2	-0.3	6		
	VREF, DROOP, DRVL1, DRVL2, IMON, PG, PGD	-0.3	6		
	PGND, GFB	-0.3	0.3		
Operating junction temperature, T _J		-40	125	°C	
Storage junction temperature, T _{stg}		– 55	150		

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL INFORMATION

	THERMAL METRIC ⁽¹⁾	RHA (40 PIN)	UNITS
θ_{JA}	Junction-to-ambient thermal resistance	32	
θ_{JB}	Junction-to-board thermal resistance	10	°C/W
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	3.4	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range, all voltages wrt GND (unless otherwise noted)

		MIN	TYP MA	X UNIT
Committee	Conversion voltage (no pin assigned)	3	2	8 V
Supply voltages	V5IN, V5FILT	4.5	5.	
	VBST1, VBST2	-0.1	3	4
Voltage range, conversion pins	DRVH1, DRVH2	-0.8	3	4 V
Pillo	LL1, LL2	-0.8	2	8
Voltage range, 5-V pins	CSN1, CSN2, CSP1, CSP2, DROOP, DRVL1, DRVL2, IMON, MODE, OSRSEL PG, PGD, SLEW, THRM, TONSEL, TRIPSEL, VREF, VFB	-0.1	5.	5 V
Voltage range, 3.3-V pins	EN	-0.1	3.	6 V
Voltage range, VCCP I/O pins	PCNT, VID0, VID1, VID2, VID3, VID4, VID5, VID6, VID7, THAL	-0.1	1.	3 V
Ground pins	PGND, GFB	-0.1	0.	1
Electrostatic Discharge	Human body model (HBM)	2		1.77
Protection (ESD)	Charged device model (CDM)	1.5		kV
Operating free air temperatur	re, T _A	-10	10	5 °C

⁽²⁾ All voltage values are with respect to the network ground terminal unless otherwise noted.



ELECTRICAL CHARACTERISTICS

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY: C	URRENTS, UVLO AND POWER-ON RE	ESET				
I _{V5}	V5IN + V5FILT supply current	$V_{DAC} < V_{VFB} < V_{DAC} + 100 \text{ mV}, \text{ EN = HI}$		2.3	4	mA
I _{V5STBY}	V5IN + V5FILT standby current	EN = LO			1	μΑ
V _{UVLOH}	V5FILT UVLO OK threshold	V_{V5FILT} = V_{V5IN} , V_{VFB} < 200 mV, Ramp up; V_{EN} = HI; Switching begins	4.25	4.4	4.5	V
V_{UVLOL}	V5FILT UVLO fault threshold	$\begin{split} V_{V5FILT} = V_{V5IN}. & \text{ Ramp down; } V_{EN} = HI, V_{VFB} = 100 \text{mV}, \\ & \text{Restart if 5 V falls below } V_{POR} \text{then rises} > V_{UVLOH} \text{is} \\ & \text{toggled with 5 V} > V_{UVLOH} \end{split}$	4	4.2	4.3	V
V_{POR}	V5FILT fault latch reset threshold	$V_{V5FILT} = V_{V5IN}$, Ramp Down, EN = HI, Can restart if 5-V goes up to V_{UVLOH} and no other faults present	1.4	1.9	2.3	V
REFERENC	ES: DAC, VREF, VBOOT AND DRVL D	DISCHARGE				
V _{VIDSTP}	VID step size	Change VID0 HI to LO to HI		6.25		mV
V _{DAC1}	VFB no load active	0.750 V ≤ V _{VFB} ≤ 1.250 V	-1.35%		1.35%	
V _{DAC2}	VFB no load active/sleep	0.500 V ≤ V _{VFB} ≤ 0.750 V	-11		11	mV
V _{DAC3}	VFB deeper sleep	0.300V ≤ V _{VFB} ≤ 0.500 V	-14		14	mV
V_{DAC4}	VFB above microcontroller VID	1.250 V ≤ V _{VFB} ≤ 1.6 V	-1.35%		1.35%	
V_{VREF}	VREF output	$4.5 \text{ V} \le \text{V}_{\text{V5FILT}} \le 5.5 \text{ V}, \text{I}_{\text{REF}} = 0$	1.665	1.700	1.750	V
V _{VREFSRC}	VREF output source	I _{REF} = 0 μA to 250 μA	-9	-3		mV
V _{VREFSNK}	VREF output sink	I _{REF} = -250 μA to 0 μA		10	35	mV
V_{VBOOT}	Internal VFB initial boot voltage	Initial DAC boot voltage	0.99	1.00	1.01	V
VOLTAGE S	SENSE: VFB AND GNDSNS					
I _{VFB}	VFB input bias current	Not in fault, disable or UVLO; V _{VFB} = 2 V, GFB = 0 V		9	40	μA
I_{VFBDQ}	VFB input bias current, discharge	Fault, disable or UVLO, V _{VFB} = 100 mV	90	125	175	μΑ
I_{GFB}	GNDSNS input bias current	Not in fault, disable or UVLO; V _{VFB} = 2 V, GSNS = 0 V	-40	-8		μΑ
V_{DELGND}	GNDSNS differential			±300		mV
A _{GAINGND}	GNDSNS/GND gain		0.995	1.000	1.011	V/V
V_{VFBCOM}	VFB common mode input		-0.3		2	V
CURRENT	MONITOR					
V _{IMONLK}	Zero-level current output $\Sigma\Delta CS = 0$ mV, $R_{IMON} = 12.7$ k Ω		0	5	150	mV
V _{IMONLO}	Low-level current output	$\Sigma \Delta CS = 10$ mV, $R_{IMON} = 12.7$ kΩ	202	250	302	mV
V _{IMINMID}	Mid-level current output	$\Sigma \Delta CS = 20$ mV, R _{IMON} = 12.7 kΩ	460	500	538	mV
V _{IMONHI}	High-level current output $\Sigma \Delta CS = 40 \text{ mV}, R_{\text{IMON}} = 12.7 \text{ k}\Omega$		958	1000	1058	mV
K _{IMON}	Gain factor			2		μΑ/mV
I _{IMONSRC}	Current monitor source	ΣΔCS = 60 mV	108		130	μA
V _{IMONSNK}	Current monitor clamp	$\Sigma\Delta$ CS = 40 mV, R _{IMON} = OPEN	1.02		1.11	V



ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
CURRENT S	SENSE: OVERCURRENT, ZERO CROS	SING, VOLTAGE POSITIONING AND PHASE BALANCING					
		V _{TRIPSEL} = GND, R _{SLEW} to GND	8.2		13.5		
		V _{TRIPSEL} = REF, R _{SLEW} to GND	11.4		16.8		
		V _{TRIPSEL} = 3.3 V, R _{SLEW} to GND	14.5		20.3		
	OCP voltage set	V _{TRIPSEL} = V _{V5FILT} , R _{SLEW} to GND	19.3		25.3	.,	
OCPP	(valley current limit)	V _{TRIPSEL} = GND, R _{SLEW} to VREF	24.0		30.5	mV	
		V _{TRIPSEL} = REF, R _{SLEW} to VREF	30.2		37		
		V _{TRIPSEL} = 3.3 V, R _{SLEW} to VREF	38.1		45.5		
		$V_{TRIPSEL} = V_{V5FILT}$, R_{SLEW} to VREF	48.9		57		
		V _{TRIPSEL} = GND, R _{SLEW} to GND	12.5		17.7		
		V _{TRIPSEL} = REF, R _{SLEW} to GND	15.8		21.5		
		V _{TRIPSEL} = 3.3 V, R _{SLEW} to GND	19.2		25		
V _{OCPN}	Negative OCP voltage	V _{TRIPSEL} = V _{V5FILT} , R _{SLEW} to GND	25.5		31.5		
	(minimum magnitude)	V _{TRIPSEL} = GND, R _{SLEW} to VREF	32.1		38.3	mV	
		V _{TRIPSEL} = REF, R _{SLEW} to VREF	40.5		46.7		
		V _{TRIPSEL} = 3.3 V, R _{SLEW} to VREF	51.9		58.5	1	
		V _{TRIPSEL} = V _{V5FILT} , R _{SLEW} to VREF	64.9		71.8		
/ _{OCPCC}	Channel-to-channel OCP matching	(CSP1–CSN1) – (CSP2–CSN2) at OCP for each channel		±1.0		mV	
cs	CS pin input bias current	CSPx and CSNx	-1	0.2	1	μA	
M-DROOP	Droop amplifier transconductance	V _{VSNS} = 1 V	482	500	522	μs	
DROOP	Droop amplifier sink/source current		50	100	150	μΑ	
/ _{DCLAMPN}	Droop amplifier clamp voltage (negative)	(V _{VREF} - V _{DROOP})		46		mV	
/ _{DCLAMPP}	Droop amplifier clamp voltage (positive)	(V _{DROOP} – V _{VREF})		1.2		V	
BAL_TOL	Internal current share tolerance	$V_{DAC} = 0.750 \text{ V};$ $V_{CSP1} - V_{CSN1} = V_{CSP2} - V_{CSN2} = V_{OCPP_MIN}$	-3%		3%		
A _{CSINT}	Internal current sense gain	Gain from CSPx – CSNx to PWM comparator	5.93		6.11	V/V	
RIVERS: H	IIGH-SIDE, LOW-SIDE, CROSS CONDU	JCTION PREVENTION AND BOOST RECTIFIER					
	PD///	$(V_{VBSTx} - V_{LLx}) = 5 \text{ V}$, HI state, $(V_{VBST} - V_{DRVH}) = 0.1 \text{ V}$		1.2	2.5	_	
R _{DRVH}	DRVH on-resistance	$(V_{VBSTx} - V_{LLx}) = 5 \text{ V, LO state, } (V_{DRVH} - V_{LL}) = 0.1 \text{ V}$		0.8	2.5	Ω	
	DD)/// : 1 / (1)	$V_{DRVHx} = 2.5 \text{ V}, (V_{VBSTx} - V_{LLx}) = 5 \text{ V}, \text{ source}$		2.2			
DRVH	DRVH sink/source current ⁽¹⁾	$V_{DRVHx} = 2.5 \text{ V}, (V_{VBSTx} - V_{LLx}) = 5 \text{ V}, \text{ sink}$		2.2		Α	
		DRVHx 10% to 90% C _{DRVHx} = 3 nF		17	30		
DRVH	DRVH transition time	DRVHx 90% to 10% C _{DRVHx} = 3 nF		13	30	ns	
	DD/# : .	HI state, $(V_{V5IN} - V_{DRVL}) = 0.1 \text{ V}$		0.9	2	_	
R _{DRVL}	DRVL on-resistance	LO state, (V _{DRVL} – V _{PGND}) = 0.1 V		0.4	1	Ω	
	DD) (1	V _{DRVLx} = 2.5 V, source		2.7			
DRVL	DRVL sink/source current ⁽¹⁾	V _{DRVLx} = 2.5 V, sink		8		Α	
	DDV4 4 37 47	DRVLx 90% to 10%, CDRVLx = 3 nF		10	30		
DRVL	DRVL transition time	DRVLx 10% to 90%, CDRVLx = 3 nF		14	30	ns	
	5.	LLx falls to 1V to DRVLx rises to 1 V	14	19	29		
NONOVLP	Driver non-overlap time	DRVLx falls to 1V to DRVHx rises to 1 V	21	29	40	ns	
/ _{FBST}	BST rectifier forward voltage	$V_{V5IN} - V_{VBST}$, $I_F = 5$ mA, $T_A = 25$ °C	0.6	0.7	0.8	V	
BSTLK	BST rectifier leakage current	V _{VBST} = 34 V, V _{LL} = 28 V		0.1	1	μA	

⁽¹⁾ Specified by design. Not production tested.



ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OVERSHOO	T REDUCTION (OSR) THRESHOLD	SETTING				
		V _{OSRSEL} = GND	78	106	135	
V	000	V _{OSRSEL} = REF	111	140	174	\/
V_{OSR}	OSR voltage set	V _{OSRSEL} = 3.3 V	151	186	224	mV
		V _{OSRSEL} = V5FILT		OFF		
V _{OSRHYS}	OSR voltage Hysteresis ⁽²⁾	All settings		20		mV
TIMERS: SL	EW RATE, SLEW, ON-TIME AND I/O	TIMING				
I _{SLEW 1}	R _{SLEW} to GND current	R_{SLEW} = 125 k Ω from SLEW to GND	9.9	10	10.2	μA
I _{SLEW 2}	R _{SLEW} to VREF current	$R_{SLEW} = 45 \text{ k}\Omega \text{ from VREF to SLEW}$	9.5	10.2	10.8	μA
t _{STARTUP}	VFB startup time	I_{SLEW} = 10 μA , No Faults, Time from EN to VSNS = VBOOT – 12%	0.60	0.80	0.90	ms
SL _{STRT}	VFB slew soft-start	I _{SLEW} = 10 μA , EN goes HI (soft-start)	1.3	1.6	1.9	mV/μs
SR	VFB slew rate	I _{SLEW} = 10 μA	10	12.5	15	mV/μs
t _{PGDPO}	PGD power-on delay time	Time from PG going low to PG going high	0.4	0.7	1	ms
t _{PGDDGLTO}	PGD deglitch time	Time from VFB out of +300 mV V _{DAC} boundary to PGOOD low	40	74	100	μs
t _{PGDDGLTU}	PGD deglitch time Time from VFB out of –300 mV V _{DAC} boundary to PGO low		50	105	150	μs
		V _{TON} = GND, V _{LLx} = 12 V, V _{VFB} = 1 V	315	400	465	
		V _{TON} = V _{REF} , V _{LLx} = 12 V, V _{VFB} = 1 V	215	260	300	ns
t _{TON}	On-time control	V _{TON} = 3.3 V, V _{LLx} = 12 V, V _{VFB} = 1 V	170	200	230	
		V _{TON} = V _{V5FILT} , V _{LLx} = 12 V, V _{VFB} = 1	145	170	190	
t _{MIN}	Controller minimum OFF time	Fixed value	70	102	125	ns
t _{VIDDBNC}	VID debounce time ⁽²⁾		100			ns
t _{PSIDBNC}	PCNT debounce Time ⁽²⁾		100			ns
t _{VCCVID}	VID change to VFB Change ⁽²⁾				600	ns
t _{VRONPGD}	EN low to PGD low		20	74	100	ns
t _{PGDVCC}	PGD low to VFB change (2)				100	ns
t _{VRTDGLT}	THAL deglitch time		0.3	1	3	ms
	N: OVP, PGOOD, VR, VR_TT FAULT	S OFF AND INTERNAL THERMAL SHUTDOWN				
V _{OVPH}	Fixed OVP voltage	VFB > V _{OVPH} for 1 μs, DRVL turns ON	1.6		1.8	V
V _{PGDH}	PGD high threshold	Measured at the VFB pin wrt / VID code, device latches OFF, begins soft-stop	180		258	mV
V_{PGDL}	PGD low threshold	Measured at the VFB pin wrt / VID code, device latches off, begins soft-stop	-367		-273	mV
V _{THRM}	Thermal shutdown voltage	Measured at THERM; THAL goes LO	0.69	0.75	0.81	V
I _{THRM}	THERM current	Measure I _{THERM} to GND	57.5	61	67.5	μA
V _{NOFLT}	All faults OFF	THRM > V5FILT + V _{TH} ; not latched	4.75	4.9	5	V
TH _{INT}	Internal controller thermal shutdown ⁽²⁾	Latch off controller		160		°C

⁽²⁾ Specified by design. Not production tested.

ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT			
LOGIC PINS: I/O VOLTAGE AND CURRENT									
V _{VRTTL}	THAL pull-down voltage	Pul- down voltage with 20-mA sink current		0.15	0.40	V			
I _{VRTTLK}	THAL leakage current	Hi-Z leakage current, Apply 5-V in off state	-2	0.2	2	μA			
V _{CLKPGL}	PG, PG pull-down voltage	Pull-down voltage with 3-mA sink current		0.1	0.4	V			
I _{CLKPGLK}	PG, PGOOD leakage current	Hi-Z leakage current, Apply 5-V in off state	-2	0.1	2	μA			
V _{VCCPH}	I/O LV logic high	PCNT, EN, VID0, VID1, VID2, VID3, VID4, VID5, VID6,	0.83			V			
V _{VCCPL}	I/O LV logic low	VID7			0.3	V			
I _{VCCPLK}	I/O LV leakage	Leakage current, $V_{VID} = V_{PCNT} = 1 \text{ V}$; $V_{EN} = 0 \text{ V}$	-1.00	0.01	1.00	μA			
I _{VIDLK}	I/O LV leakage	Leakage current, V _{VID} = V _{PCNT} = 1 V; EN = 3.3 V	5	10	15	μΑ			
I _{ENH}	I/O 3.3-V leakage	Leakage current, V _{EN} = 3.3 V	10		25	μΑ			
I _{VIDL}		$\begin{array}{l} V_{VID0} = V_{VID1} = V_{VID2} = V_{VID3} = V_{VID4} = V_{VID5} = V_{VID6} = V_{VID7} = 0 \\ V, \ V_{EN} = 3.3 \ V \end{array}$	-3	-1.5	1	μΑ			
I _{SELECT}		V _{TRIPSEL} = V _{OSRSEL} = V _{TONSEL} = 5 V	-2	1.5	5	μΑ			
I _{CTRL}		V _{PCNT} = 0 V; V _{EN} = 3.3 V	-1		1	μΑ			
I _{MODEL}		V _{MODE} = 0 V	- 5		5	μΑ			
I _{MODEH}		V _{MODE} = 5 V	10		40	μΑ			

DEVICE INFORMATION

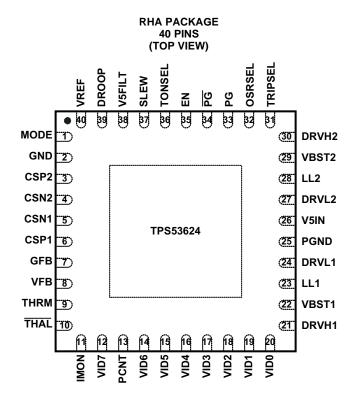


Table 1. PIN FUNCTIONS

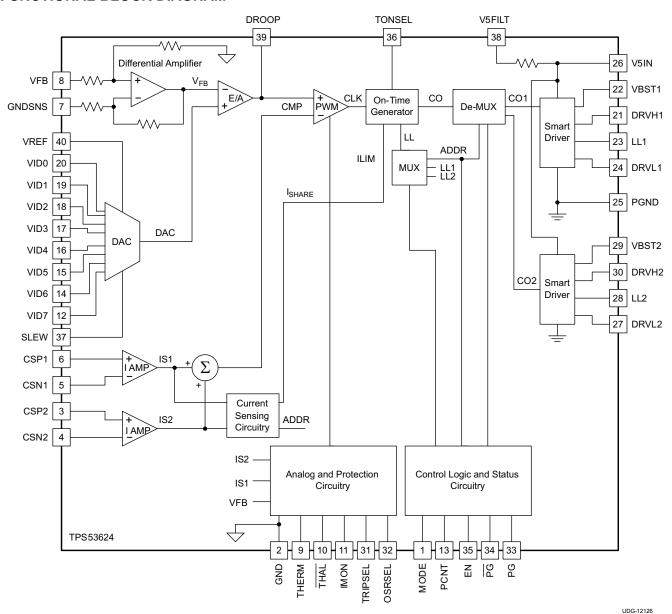
TERMINAL			DECORPTION
NAME	NO.	1/0	DESCRIPTION
CSP1	6	I	Positive current sense inputs. Connect to the most positive node of current sense resistor or inductor DCR
CSP2	3	I	sense R-C network.
CSN1	5	I	Negative current sense inputs. Connect to the most negative node of current sense resistor or inductor DCR
CSN2	4	ı	sense RC network.
DROOP	39	0	Output of g _M error amplifier. A resistor to VREF sets the droop gain. A capacitor to VREF helps shape the transient response.
DRVH1	21	0	Link side Nickersel MOCFET rate drive systems
DRVH2	30	0	High-side N-channel MOSFET gate drive outputs.
DRVL1	24	0	Complyana to Ni phonosi MOCEET gate deitre autoute
DRVL2	27	0	Synchronous N-channel MOSFET gate drive outputs.
EN	35	I	Controller enable. 3.3-V I/O level; 100-ns de-bounce. Logic high 3.3-V enables the controller. Logic low stops the controller.
GND	2	_	Return for analog circuits.
GFB	7	I	Voltage sense return tied directly to GND of the microprocessor. Tie to GND with a $100-\Omega$ resistor to close feedback when the microprocessor is not in the socket.
IMON	11	0	Current monitor output. $V_{IMON} = \Sigma V_{ISENSE} \times K \times R_{IMON}$. Reference R_{IMON} to GNDSNS. Voltage is clamped at 1.1-V maximum.
LL1	23	I/O	Historia National MOOFFT and adding a land for a death a safe discount
LL2	28	I/O	High-side N-channel MOSFET gate drive return. Also, input for adaptive gate drive timing.
MODE	1	_	Tie to GND to select CPU mode.
OSRSEL	32	0	Overshoot reduction (OSR) setting. The OSR threshold can be selected or OSR can be disabled.
PG	34	0	Negative active power good output; Open drain. Transitions low of approximately 50 ms after VOUT reaches the VID level. Leave open if unused.



Table 1. PIN FUNCTIONS (continued)

TERMINAL			DECORIDEION		
NAME	NO.	I/O	DESCRIPTION		
PGND	25		Synchronous N-channel MOSFET gate drive return.		
PG	33	0	Power good output; Open-drain. 6ms delay from voltage reaching the power good threshold. Leave open if unused		
PCNT	13	I	Single or dual phase control. 1-V I/O level. A low is single phase mode.		
SLEW	37	ı	Precision current set-point for slew rate control. Tie the R_{SLEW} resistor to GND for the low OCP range; tie R_{SLEW} to VREF for the high OCP range.		
THAL	10	0	Thermal flag open drain output - active low. Fall time < 100ns with 56Ω pull-up to 1V. 1ms de-glitch filter.		
THRM	9	I/O	Thermal sensor input. An internal, 60-µA current source flows into an NTC thermistor connected to GND. The voltage threshold is 0.75 V. Also is a <i>faults off</i> input, (THERM = V5FILT) for debug mode.		
TONSEL	36	ı	On-time selection pin. The operating frequency can be set between 200 kHz and 500 kHz in 100 kHz steps. Frequency can be changed during operation.		
TRIPSEL	31	ı	Overcurrent protection (OCP) setting. TRIPSEL is set with the R _{SLEW} connection. The valley current limit at the CS inputs can be selected in a range from approximately 10 mV to approximately 50 mV.		
VBST1	22	ı	High side Nichered MOCFFT heatetree velkers invite		
VBST2	29	ı	High-side N-channel MOSFET bootstrap voltage inputs.		
VID0	20				
VID1	19				
VID2	18				
VID3	17	,	VID bits (MSB to LSB). 1-V I/O level; 100ns de-bounce		
VID4	16	'	VID bits (WISB to ESB). 1-V I/O level, 1001is de-boulice		
VID5	15				
VID6	14				
VID7	12				
V5FILT	38	I	5-V power input for control circuitry. Has internal 3-Ω resistor to 5VIN; bypass to GND with a ≥1-μF ceramic capacitor.		
V5IN	26	ı	5-V power input for drivers; bypass to PGND with ≥2.2 µF ceramic capacitor.		
VREF	40	0	1.7-V, 250-μA voltage reference. Bypass to GND with a 0.22-μF ceramic capacitor.		
VFB	8	I	Voltage sense line tied directly to V_{CORE} of the microprocessor. Tie to V_{OUT} with a 100- Ω resistor to close feedback when the microprocessor is not in the socket.		
Thermal Pad			Connect directly to system GND plane with multiple vias.		

FUNCTIONAL BLOCK DIAGRAM





APPLICATION DIAGRAMS

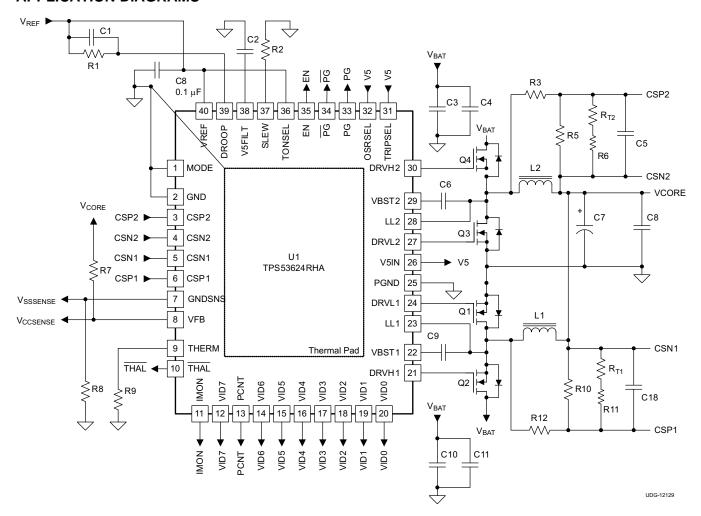


Figure 1. Inductor DCR Current Sense Application Diagram



Application Circuit List of Materials

Recommended part numbers for key external components for the circuits in Figure 1 is listed in Table 2. These components have passed applications tests.

Table 2. Key External Component Recommendations

FUNCTION	MANUFACTURER	COMPONENT NUMBER
High-side MOSFET	Infineon	BSC080N03MSG
Low-side MOSFET (x2)	Infineon	BSC030N03MSG
	Panasonic	ETQP4LR36AFC
Inductors	Tokin	MPCG1040LR36
	Toko	FDUE10140D-R36M
	Panasonic	EEFLX0D331R4
Bulk Output Capacitors	Sanyo	2TPLF330M5
	Kemet	T528Z337M2R5ATE005-6666
Coromio Output Conscitors	Panasonic	ECJ2FB0J106K
Ceramic Output Capacitors	Murata	GRM21BR60J106KE19L
NTC Thermistors	Panasonic	ERTJ1VV154J
NTC THEITHISTOIS	Murata	NCP18XF151J03RB



DETAILED DESCRIPTION

FUNCTIONAL OVERVIEW

The TPS53624 is a D-CAP+™ mode adaptive on-time converter. The output voltage is set using a DAC that outputs a reference in accordance with the 8-bit VID code defined in Table 5. VID-on-the-fly transitions are supported with the slew rate controlled by a single resistor on the SLEW pin. Two powerful integrated drivers support output currents in excess of 50 A. The converter enters single phase mode under PCNT control to optimize light-load efficiency. Four switching frequency selections are provided in 100-kHz increments from 200 kHz to 500 kHz per phase to enable optimization of the power chain for the cost, size and efficiency requirements of the design. (See Table 3)

•	•
TONSEL VOLTAGE (V _{TONSEL}) (V)	FREQUENCY (kHz)
GND (0)	200
VREF (1.7)	300
3.3	400
5	500

Table 3. Frequency Selection Table

In adaptive on-time converters, the controller varies the on-time as a function of input and output voltage to maintain a nearly constant frequency during steady-state conditions. In conventional voltage-mode constant on-time converters, each cycle begins when the output voltage crosses to a fixed reference level. However, in the TPS53624, the cycle begins when the current feedback reaches an error voltage level which is the amplified difference between the DAC voltage and the feedback voltage.

This approach has two advantages:

- 1. The amplifier DC gain sets an accurate linear load-line; this is required for CPU core applications.
- 2. The error voltage input to the PWM comparator is filtered to improve the noise performance.

In a steady-state condition, the two phases of the TPS53624 switch 180° out-of-phase. The phase displacement is maintained both by the architecture (which does not allow both hig-side gate drives to be on in any condition) and the current ripple (which forces the pulses to be spaced equally). The controller forces current sharing adjusting the on-time of each phase. Current balancing requires no user intervention, compensation, or extra components.

Multi-Phase, PWM Operation

Referring to the Functional Block Diagram and , in dual-phase steady state, continuous conduction mode, the converter operates as follows:

Starting with the condition that both high-side MOSFETs are off and both low-side MOSFETs are on, the summed current feedback (V_{CMP}) is higher than the error amplifier output (V_{DROOP}). V_{CMP} falls until it hits V_{DROOP} , which contains a component of the output ripple voltage. The PWM comparator senses where the two waveforms cross and triggers the on-time generator.

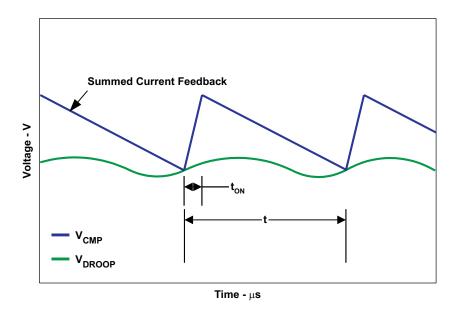


Figure 2. D-CAP+ Mode Basic Waveforms

The summed current feedback is an amplified and filtered version of the CSPx and CSNx inputs. The TPS53624 provides dual independent channels of current feedback to increase the system accuracy and reduce the dependence of circuit performance on layout compared to an externally summed architecture.

PWM Frequency and Adaptive on Time Control

The on-time (at the LL node) is determined by Equation 1.

$$t_{ON} = \left(\frac{V_{OUT}}{V_{IN}}\right) \times \left(\frac{1}{f_{SEL}}\right) + 30 \,\text{ns}$$

where

•
$$f_{SEL}$$
 is the frequency selected by the connection of the TONSEL pin (1)

The on-time pulse is sent to the high-side MOSFET. The inductor current and summed current feedback rise to their maximum value, and the multiplexer and de-multiplexer switch to the next phase. Each ON pulse is latched to prevent double pulsing.

The current sharing circuitry compares the average values of the individual phase currents, then adds or subtracts a small amount from each on-time in order to bring the phase currents into line. No user design is required.

Accurate droop is provided by the finite gain of the droop amplifier. The calculation for output voltage droop, V_{DROOP} is shown in Equation 2.

$$V_{DROOP} = \frac{R_{CS} \times A_{CS} \times \sum I(L)}{R_{DROOP} \times G_M}$$

where

- R_{CS} is the effective current sense resistance, regardless if a sense resistor or inductor DCR is used
- A_{CS} is the gain of the current sense amplifier
- ΣI(L) is the DC sum of inductor currents
- R_{DROOP} is the value of resistor from the DROOP pin to VREF
- G_M(droop) is the GM of the droop amplifier

(2)



(3)

The capacitor in parallel with R_{DROOP} matches the slew rate of the DROOP pin with the current feedback signals to prevent *ring-back* during transient load conditions.

$$C_{DROOP} = \frac{R_{LL} \times \Delta I_{OUT} \times g_{M} \times L}{R_{CS} \times A_{CS} \times D_{MAX} \times V\left(L\right)} - 30 \, pF$$

where

- R_{LL} is load-line slope defined by proicessor mnufacturer
- ΔI_{OUT} is maximum dynamic load current for the processor
- $D_{MAX} = t_{ON} / t_{ON} + t_{OFF(min)}$
- V(L) is the voltage across the inductor (V_{BAT} V_{CORE}).

The 30-pF term accounts for the slew rate limit of the amplifier without external capacitance.

AutoBalance Current Sharing

The basic mechanism for current sharing is to sense the average phase current, then adjust the pulse width of each phase to equalize the current in each phase. The block diagram is shown in Figure 3.

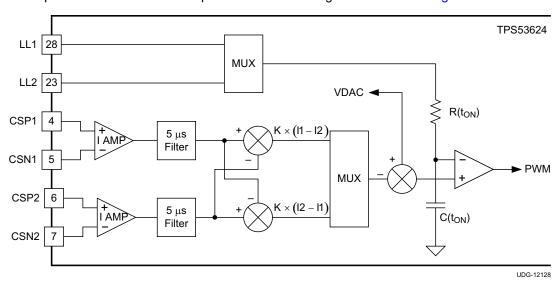


Figure 3. Current Sharing Block Diagram

Figure 3 also shows the TI D-CAP+ $^{\text{TM}}$ constant on-time modulator. The PWM comparator (not shown) starts a pulse when the feedback voltage meets the reference. This pulse turns on the gate of the high-side MOSFET. After the MOSFET turns on, the LL voltage for that phase is driven up to the battery input. This charges $C(t_{ON})$ through $R(t_{ON})$. The pulse is terminated when the voltage at $C(t_{ON})$ matches the t_{ON} reference, normally the DAC voltage (V_{DAC}) .

The circuit operates in the following fashion, using Figure 3 as the block diagram and to show the circuit action at the level of an individual pulse (PWM1). First assume that the 5 μ s averaged value of I1 = I2. In this case, the PWM modulator terminates at VDAC, and the normal pulse width is delivered to the system. If instead, I1 > I2, then an offset is subtracted from VDAC, and the pulse width for phase one is shortened, reducing the current in phase one to compensate. If I1 < I2, then a longer pulse is produced, again compensating on a pulse-by-pulse basis.

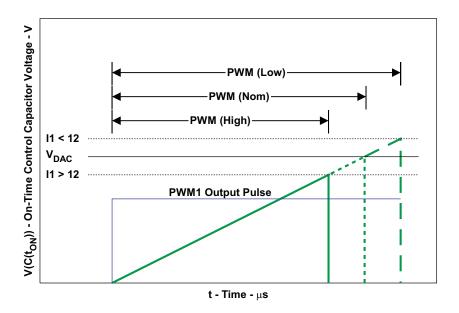


Figure 4.

Because the increase in pulse width is proportional to the difference between the actual phase current and the ideal current, the system converges smoothly to equilibrium. Because the filtering is so much lighter than conventional current sharing schemes, the settling time is very fast. Analysis shows the response to be single pole with a bandwidth of approximately 60 kHz.

The speed advantage of the TPS53624 is beneficial because processors quickly move from full speed to idle and back to save power when processing light and moderate loads. A multi-phase converter that takes milliseconds to implement current sharing is never in equilibrium and thermal hot-spots can result. The TPS53624 allows rapid dynamic current and output voltage changes while maintaining current balance.

Overshoot Reduction (OSR) Feature

The problem of overshoot in low duty-cycle synchronous buck converters results from the output inductor having a small voltage (V_{CORF}) with which to respond to a transient load release.

In Figure 5, a single phase converter is shown for simplicity. In an ideal converter, with the common values of 12-V input and 1.2-V output, the inductor has 10.8 V (12 V - 1.2 V) to respond to a transient step, and 1.2 V to respond once the load releases.

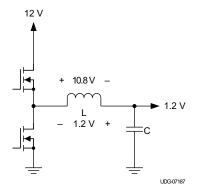


Figure 5. Synchronous Converter

TEXAS INSTRUMENTS

Figure 6 shows a two-phase converter. The energy in the inductor is transferred to the capacitance on the V_{CORE} node above and the output voltage (green trace) overshoots the desired level (lower cursor, also green). In this case, the magnitude of the overshoot is approximately 40 mV. The LLx waveforms (yellow and blue traces) remain flat during the overshoot, indicating the DRVLx signals are on.

The performance of the same dual phase circuit, but with OSR enabled is shown in Figure 7. In this case, the low side FETs shut off when overshoot is detected and the energy in the inductor is partially dissipated by the body diodes. The overshoot is reduced by 25 mV. The dips in the LLx waveforms show the DRVLx signals are OFF only long enough to reduce the overshoot.

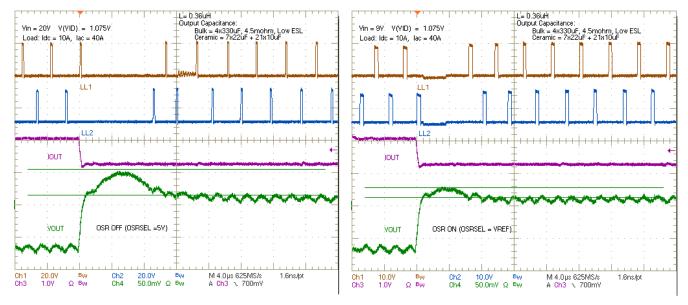


Figure 6. Circuit Performance Without Overshoot Reduction

Figure 7. Transient Release Performance Improved with Overshoot Reduction

Implementation

OSR is implemented using a comparator between the DROOP and ISUM nodes. To implement OSR, simply terminate the OSRSEL pin to the desired voltage to set the threshold voltage for the comparator. The settings are:

- GND = Minimum voltage (Maximum reduction)
- VREF = Medium voltage
- +3.3V = Maximum voltage
- 5V = OSR off

Use the highest setting that provides the desired level of overshoot reduction to eliminate the possibility of false OSR operation.

Light Load Power Saving Features

The TPS53624 has several power saving features to provide excellent efficiency over a very large load range. This feature is implemented with PCNT pin.. This pin is a VCCP I/O level. A LO on this pin puts the converter into single phase mode, thus eliminating the quiescent power of phase two when high power is not needed.

In addition, the TPS53624 has an automatic pulse skipping *skip* mode. Regardless of the state of the logic inputs, the converter senses negative inductor current flow and prevents it by shutting off the low-side MOSFET(s). This saves power by eliminating recirculating current.

MOSFET Drivers

The TPS53624 incorporates a pair of strong, high-performance gate drives with adaptive cross-conduction protection. The driver uses the state of the DRVLx and LLx pins to be sure the high-side or low-side MOSFET is off before turning the other on. Fast logic and high drive currents (up to 8 A typical!) quickly charge and discharge MOSFET gates to minimize dead-time to increase efficiency. The high-side gate driver also includes an internal P-N junction *boost* diode, decreasing the size and cost of the external circuitry. For maximum efficiency, this diode can be bypassed externally by connecting Schottky diodes from V5IN (anode) to VBSTx (cathode).

Voltage Slewing

The TPS53624 ramps the internal DAC up and down as the VID is changing. These timings are independent of switching frequency, as well as output resistive and capacitive loading. The slew rate is set by a resistor from the SLEW pin to AGND ($R_{SI\,EW}$). $R_{SI\,EW}$ sets both the slew rate and the soft-start rate.

$$R_{SLEW} = \frac{K_{SLEW} \times V_{SLEW}}{SR}$$

where

- $K_{SLEW} = 1.25 \times 10^9$
- V_{SLEW} is equal to the slew reference V_{SLEWREF}when R_{SLEW} is tied to GND

Connecting R_{SLEW} to VREF enables the high range of overcurrent protection and changes V_{SLEW} in Equation 4 to 0.45 V (VREF – $V_{SLEWREF}$). The soft-start rate is 1/8 the slew rate.

At start-up the VID code should be stable at the time EN goes high. For example, the V_{VID} for IMVP6.5 is 1.1 V. The soft-start time to V_{BOOT} is shown in Equation 5.

$$t_{SS} = \frac{1.1V \times 8}{SR} (s)$$
 (5)

Protection Features

The TPS53624 features full protection of the converter power chain as well as the system electronics.

Input Undervoltage Protection (UVLO)

The TPS53624 continuously monitors the voltage on the V5FILT pin to ensure the value is high enough to bias the devices properly and provide sufficient gate drive potential to maintain high efficiency. The converter starts with approximately 4.4 V and has a nominal 200 mV of hysteresis. This function is not latched, therefore removing and restoring 5-V power to the device resets it. The power input (V_{IN}) does not include a UVLO function, so the circuit runs with power inputs down to approximately $3 \times V_{CORE}$.

Power Good Signals

The TPS53624 has two open-drain powergood pins. PGD and PG have the following nominal thresholds:

- High: V_{DAC} + 200 mV
- Low: V_{DAC} 300 mV

The differences are:

- PG transitions active low shortly (approxiimately 50 μs) after V_{OUT} reaches the V_{ID} voltage on power-up.
- PGD rises at the same time as PG reaches the power good threshold defined above. PGD is high when
 power is good and low when power is not good.

Both power good signals go inactive when the EN pin is pulled low or an undervoltage condition on V5IN is detected. Both are also *masked* during DAC transitions to prevent false triggering during voltage slewing.

Output Overvoltage Protection (OVP)

In addition to the power good function described above, the TPS53624 has additional OVP and UVP thresholds and protection circuits.

An OVP condition is detected when VOUT is > 200 mV greater than V_{DAC} . In this case, the converter sets PGD signals inactive and then latches OFF. The converter remains in this state until the device is reset by cycling either V5IN or EN

However, because of the dynamic nature of VR systems, the +200 mV OVP threshold is *blanked* much of the time. In order to provide protection to the processor 100% of the time, there is a second OVP level fixed at 1.55 V which is always active. If the fixed OVP condition is detected, the PGD signals are forced inactive and the DRVLx signals are driven HI. The converter remains in this state until either V5IN or EN are cycled.

Output Undervoltage Protection (UVP)

Output undervoltage protection works in conjunction with the current protection described below. If VOUT drops below the low PGD threshold for 80 µs, then the drivers are turned OFF until either V5IN or EN are cycled.

Current Protection

Two types of current protection are provided in the TPS53624.

- Overcurrent protection (OCP)
- Negative overcurrent protection

Overcurrent Protection (OCP)

The TPS53624 uses a *valley* current limiting scheme, so the ripple current must be considered. The DC current value at OCP is the OCP limit value plus half of the ripple current. Current limiting occurs on a phase-by-phase and pulse-by-pulse basis. If the voltage between CSPx and CSNx is above the OCP value (selected by combination of TRIPSEL pin connection and R_{SLEW} termination), the converter holds off the next ON pulse until it drops below the OCP limit. For inductor current sensing circuits, the voltage between CSPx and CSNx is the inductor DCR value multiplied by the resistor divider which is part of the NTC compensation network. As a result, a wide range of OCP values can be obtained by changing the resistor divider value. In general, use the highest TRIPSEL setting possible with the least attenuation in the resistor divider to provide as much signal to the device as possible. This provides the best performance for all parameters related to current feedback.

In OCP mode, the voltage droops until the UVP limit is reached. Then, the converter sets the PGD pins inactive, and the drivers are turned OFF. The converter remains in this state until the device is reset by the EN or the V5IN pin.



Settings use both the TRIPSEL pin and the R_{SLEW} termination. The eight possible OCP settings are shown in Table 4. For the levels in mV for a specific setting, see the *Electrical Characteristics* table.

Table 4. TRIPSEL Settings

ОСР		R _{SLEW} Tie	d to GND		R _{SLEW} Tied to VREF					
TRIPSEL	GND	VREF	3.3V	5V	GND	VREF	3.3V	5V		
Setting Level	1	2	3	4	5	6	7	8		

Negative Overcurrent Protection

The negative OCP circuit acts when the converter is sinking current. The converter continues to act in a *valley* mode, so to have a similar negative DC limit, the absolute value of the negative OCP set point is typically 50% higher than the positive OCP set point.

Thermal Protection

Two types of thermal protection are provided in the TPS53624

- Thermal flag open drain ouptut signal (THAL)
- Thermal shutdown

Thermal Flag Open Drain Ouptut Signal THAL

The \overline{THAL} signal is an Intel-defined open-drain signal that is used to protect the power chain. To use \overline{THAL} , place an NTC thermistor at the hottest area of the PC board and connect it to the THRM pin. THRM sources a precise 60- μ A current, and \overline{THAL} goes LO when the voltage on THERM reaches 0.7 V. Therefore, the NTC thermistor needs to be 11.7 k Ω at the trip level. A series or parallel resistor can be used to trim the resistance to the desired value at the trip level.

THAL signal does not change the operation of TPS53624

Thermal Shutdown

The TPS53624 also has an internal temperature sensor. When the temperature reaches a nominal 160°C, the device shuts down. The converter remains in this state until either V5IN or EN is cycled.

Current Monitor

The TPS53624 includes a power monitor function. The power monitor puts out an analog voltage proportional to the output power on the IMON pin.

$$V_{IMON} = A_{CS} \times GM_{IMON} \times \sum V_{CS} = K_{IMON} \times \sum V_{CS}$$

where

- K_{IMON} is given in the *Electrical Characteristics* table
- Σ V_{CS} is the sum of the voltages at the inputs to the current sense amplifiers

(6)



Single-Phase Operation

The TPS53624 is a two-phase controller. This controller can also be configured for single-phase operation. There are two ways the controller operates in single-phase mode.

- PCNT = 0 V. In this case, the controller starts up as dual-phase but goes into single-phase after start-up is completed. This mode is used for improving efficiency of a two-phase converter while operating under light load conditions.
- PCNT = 5 V. In this case, the controller operates in a complete single-phase mode. The drivers for Phase 2 are totally disabled in this mode.

In order to use the controller purely as a single-phase controller, connect PCNT to V5FILT. Also, the current sense input pins of the second phase (CSN2, CSP2) must be grounded. All the other pins of the second phase must be left open.

VID Table

The TPS53624 incorporates the 8-bit VID table shown in Table 5.

Table 5. VID Table

VID VDAC Hex OFF 1.60000 1.59375 1.58750 1.58125 1.57500 1.56875 O n O n n O 1 56250 1.55625 Α 1.55000 В 1.54375 С 1.53750 D 1.53125 Е 1.52500 F 1.51875 1.51250 n O O 1.50625 1.50000 1.49375 1.48750 n O 1.48125 1.47500 1.46875 1.46250 1.45625 1A 1.45000 1B 1.44375 1C 1.43750 1D 1.43125 1E 1.42500 1F 1.41875 1.41250 1.40625 1.40000 1.39375 1.38750 1.38125

Table 5. VID Table (continued)

Hex	7	VID 6 5 4 3 2 1 0					VDAC		
26	0	0	1	0	0	1	1	0	1.37500
27	0	0	1	0	0	1	1	1	1.36875
28	0	0	1	0	1	0	0	0	1.36250
29	0	0	1	0	1	0	0	1	1.35625
2A	0	0	1	0	1	0	1	0	1.35000
2B	0	0	1	0	1	0	1	1	1.34375
2C	0	0	1	0	1	1	0	0	1.33750
2D	0	0	1	0	1	1	0	1	1.33125
2E	0	0	1	0	1	1	1	0	1.32500
2F	0	0	1	0	1	1	1	1	1.31875
30	0	0	1	1	0	0	0	0	1.31250
31	0	0	1	1	0	0	0	1	1.30625
32	0	0	1	1	0	0	1	0	1.30000
33	0	0	1	1	0	0	1	1	1.29375
34	0	0	1	1	0	1	0	0	1.28750
35	0	0	1	1	0	1	0	1	1.28125
36	0	0	1	1	0	1	1	0	1.27500
37	0	0	1	1	0	1	1	1	1.26875
38	0	0	1	1	1	0	0	0	1.26250
39	0	0	1	1	1	0	0	1	1.25625
3A	0	0	1	1	1	0	1	0	1.25000
3B	0	0	1	1	1	0	1	1	1.24375
3C	0	0	1	1	1	1	0	0	1.23750
3D	0	0	1	1	1	1	0	1	1.23125
3E	0	0	1	1	1	1	1	0	1.22500
3F	0	0	1	1	1	1	1	1	1.21875
40	0	1	0	0	0	0	0	0	1.21250
41	0	1	0	0	0	0	0	1	1.20625
42	0	1	0	0	0	0	1	0	1.20000
43	0	1	0	0	0	0	1	1	1.19375
44	0	1	0	0	0	1	0	0	1.18750
45	0	1	0	0	0	1	0	1	1.18125
46	0	1	0	0	0	1	1	0	1.17500
47	0	1	0	0	0	1	1	1	1.16875
48	0	1	0	0	1	0	0	0	1.16250
49	0	1	0	0	1	0	0	1	1.15625
4A	0	1	0	0	1	0	1	0	1.15000
4B	0	1	0	0	1	0	1	1	1.14375
4C	0	1	0	0	1	1	0	0	1.13750



Table 5. VID Table (continued)

VID VDAC Hex 4D 1.13125 4E 1.12500 4F 1.11875 1.11250 1.10625 1.10000 1.09375 1.08750 1.08125 1.07500 1.06875 1.06250 1.05625 5A 1 05000 5B 1.04375 5C 1.03750 5D 1.03125 5E 1.02500 5F 1.01875 1.01250 1.00625 1.00000 0.99375 0.98750 0.98125 0.97500 0.96875 0.96250 0.95625 6A 0.95000 6B 0.94375 6C 0.93750 6D 0.93125 6E 0.92500 6F 0.91875 0.91250 0.90625 0.90000 0.89375 0.88750 0.88125 0.87500 0.86875 0.86250 0.85625 7A 0.85000 7B 0.84375 7C 0.83750 7D 0.83125 7E 0.82500 7F 0.81875 0.81250 0.80625 0.80000 0.79375

Table 5. VID Table (continued)

Hex	Table 5. VID Table (Continued)										
Hex					VID					VDAC	
B5	Hex	7	6	5	4	3	2	1	0	VDAC	
B86	84	1	0	0	0	0	1	0	0	0.78750	
87	85	1	0	0	0	0	1	0	1	0.78125	
87	86	1	0	0	0	0	1	1	0	0.77500	
88											
88											
BA											
BB											
BC						ł					
BD											
BE 1 0 0 0 1 1 1 0 0.72500 BF 1 0 0 0 1 1 1 1 0.71875 90 1 0 0 0 0 0 0.71250 91 1 0 0 1 0 0 0 0 0.71250 92 1 0 0 1 0 0 1 0 0.70000 93 1 0 0 1 0 0 1 1 0.69375 94 1 0 0 1 0 1 0 0 0.68375 95 1 0 0 1 0 1 0 0 1.68825 96 1 0 0 1 1 0 0 0.68625 98 1 0 0 1 1 0 0<											
8F 1 0 0 0 1 1 1 1 0.71875 90 1 0 0 1 0 0 0 0.771250 91 1 0 0 1 0 0 0 1 0.70002 92 1 0 0 1 0 0 1 0 0.70000 93 1 0 0 1 0 0 1 0 0.688750 94 1 0 0 1 0 1 0 0 0.688750 95 1 0 0 1 0 1 0 0.688750 96 1 0 0 1 0 1 1 0 0.686250 99 1 0 0 1 1 0 0 0 0.686250 99 1 0 0 1 1											
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91	8F	1	0	0	0	1	1	1	1	0.71875	
92 1 0 0 1 0 0.70000 93 1 0 0 1 0 0 1 0 0.68750 94 1 0 0 1 0 1 0 0 0.68750 95 1 0 0 1 0 1 0 1 0 1 0 1 0 1 0 1 0 1 0 1 0 0 1 0.66750 98 1 0 0 1 1 1 0 0.66250 99 1 0 0 1 1 0 0 1 0.66250 99 1 0 0 1 1 0 0 1 0.66250 99 1 0 0 1 1 0 0 1 0.66250 99 1 0 0 1 1 0 0.66250 99 1<	90	1	0	0	1	0	0	0	0	0.71250	
93 1 0 0 1 0 0 1 1 0.69375 94 1 0 0 1 0 1 0 0 0.68750 95 1 0 0 1 0 1 0 1 0.68125 96 1 0 0 1 0 1 1 0 0.68750 97 1 0 0 1 1 0 0 0.66250 98 1 0 0 1 1 0 0 0.66250 99 1 0 0 1 1 0 0 0.66250 98 1 0 0 1 1 0 0 0.64375 9C 1 0 0 1 1 1 0 0.64375 9D 1 0 0 1 1 1 0 0 0<	91	1	0	0	1	0	0	0	1	0.70625	
94 1 0 0 1 0 1 0 0 0.68750 95 1 0 0 1 0 1 0 1 0.68125 96 1 0 0 1 0 1 1 0 0.66750 97 1 0 0 1 1 1 0 0.66250 98 1 0 0 1 1 0 0 0.66250 99 1 0 0 1 1 0 0 1.66500 9B 1 0 0 1 1 0 0 0.66250 9B 1 0 0 1 1 0 0 0.63750 9B 1 0 0 1 1 1 0 0 0.63750 9B 1 0 0 1 1 1 0 0 0<	92	1	0	0	1	0	0	1	0	0.70000	
95 1 0 0 1 0 1 0.68125 96 1 0 0 1 0 1 1 0 0.67500 97 1 0 0 1 0 1 1 0 0.66250 98 1 0 0 1 1 0 0 0.66250 99 1 0 0 1 1 0 0 1 0.65000 98 1 0 0 1 1 0 1 0.65000 0 9B 1 0 0 1 1 0 1 1 0.64375 9C 1 0 0 1 1 1 0 0.64375 9C 1 0 0 1 1 1 0 0.63750 9D 1 0 0 1 1 0 0 0 0<	93	1	0	0	1	0	0	1	1	0.69375	
96 1 0 0 1 0 1 1 0 0.67500 97 1 0 0 1 0 1 1 0 0.66250 98 1 0 0 1 1 0 0 0.66250 99 1 0 0 1 1 0 0 1 0.65000 98 1 0 0 1 1 0 0 1 0.65000 9B 1 0 0 1 1 0 1 0.64375 9C 1 0 0 1 1 1 0 0.64375 9D 1 0 0 1 1 1 0 0.63750 9D 1 0 0 1 1 0 0 0.63750 9F 1 0 0 1 1 0 0 0 0<	94	1	0	0	1	0	1	0	0	0.68750	
97	95	1	0	0	1	0	1	0	1	0.68125	
98	96	1	0	0	1	0	1	1	0	0.67500	
98 1 0 0 1 1 0 0 0.66250 99 1 0 0 1 1 0 0 1 0.65625 9A 1 0 0 1 1 0 0 1 0.65000 9B 1 0 0 1 1 0 1 0 0.65000 9B 1 0 0 1 1 0 0 0.63750 9D 1 0 0 1 1 1 0 0 0.63750 9D 1 0 0 1 1 1 0 0 0.63750 9D 1 0 0 1 1 1 1 0 0 0.63125 9B 1 0 0 1 1 0.63125 9B 1 0 0 1 1 0.63125 0 0 0 0 0 0 0 0 0 0	97	1	0	0	1	0	1	1	1	0.66875	
99	98	1	0	0	1	1	0	0	0		
9A 1 0 0 1 1 0 1 0 0.65000 9B 1 0 0 1 1 0 1 1 0.64375 9C 1 0 0 1 1 1 0 0 0.63750 9D 1 0 0 1 1 1 0 0 0.63750 9E 1 0 0 1 1 1 1 0 0.62500 9F 1 0 0 1 1 1 1 1 0.66250 A0 1 0 1 0 0 0 0 0 0.61250 A1 1 0 1 0 0 0 0 0 0.6025 A2 1 0 1 0 0 0 1 0 0.6000 A3 1 0 1 0 <td></td>											
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A4 1 0 1 0 0 1 0 0 0.58750 A5 1 0 1 0 0 1 0 1 0.58125 A6 1 0 1 0 0 1 1 0 0.57500 A7 1 0 1 0 0 1 1 1 0.56875 A8 1 0 1 0 1 0 0 0.56250 A9 1 0 1 0 1 0 0 0.55625 AA 1 0 1 0 1 0 0.55625 AA 1 0 1 0 1 0 0.55000 AB 1 0 1 0 1 0 0.53750 AB 1 0 1 0 1 1 0.53125 AC 1 0	A2	1	0	1	0	0	0	1	0	0.60000	
A5 1 0 1 0 1 0.58125 A6 1 0 1 0 1 0 0.57500 A7 1 0 1 0 0 1 1 0.56875 A8 1 0 1 0 1 0 0 0.56250 A9 1 0 1 0 1 0 0 0.55625 AA 1 0 1 0 1 0 0.55625 AA 1 0 1 0 1 0 0.55625 AA 1 0 1 0 1 0 0.55000 AB 1 0 1 0 1 0 0.53750 AD 1 0 1 0 1 1 0.53125 AE 1 0 1 0 1 1 0.51875 BO 1	А3	1	0	1	0	0	0	1	1	0.59375	
A6 1 0 1 0 0 1 1 0 0.57500 A7 1 0 1 0 0 1 1 1 0.56875 A8 1 0 1 0 1 0 0 0.56250 A9 1 0 1 0 1 0 0 0.55625 AA 1 0 1 0 1 0 0 0.55000 AB 1 0 1 0 1 0 0.55000 AB 1 0 1 0 1 1 0.54375 AC 1 0 1 0 1 1 0.533750 AD 1 0 1 1 0 1 0.533750 AE 1 0 1 0 1 1 0.53125 AF 1 0 1 0 1	A4	1	0	1	0	0	1	0	0	0.58750	
A7 1 0 1 0 0 1 1 1 0.56875 A8 1 0 1 0 1 0 0 0.56250 A9 1 0 1 0 1 0 0 0.55625 AA 1 0 1 0 1 0 0.55000 AB 1 0 1 0 1 0 1 0.54375 AC 1 0 1 0 1 1 0.54375 AC 1 0 1 0 1 1 0.54375 AE 1 0 1 0 1 1 0.533750 AF 1 0 1 0 1 1 0.533750 AF 1 0 1 0 1 1 0.531875 BO 1 0 1 1 1 1 0.552500 <td>A5</td> <td>1</td> <td>0</td> <td>1</td> <td>0</td> <td>0</td> <td>1</td> <td>0</td> <td>1</td> <td>0.58125</td>	A5	1	0	1	0	0	1	0	1	0.58125	
A8 1 0 1 0 1 0 0 0 0.56250 A9 1 0 1 0 1 0.55625 1 0 1 0.55625 AA 1 0 1 0 1 0 0.55000 AB 1 0 1 0 1 0 1 0.54375 AC 1 0 1 0 1 1 0 0.53750 AD 1 0 1 0 1 1 0 0.53750 AD 1 0 1 0 1 0 1 0.53750 AB 1 0 1 0 1 0 0.53750 AD 1 0 1 0 1 0 0.53125 AE 1 0 1 0 1 1 0.51875 BO 1 0 1	A6	1	0	1	0	0	1	1	0	0.57500	
A9 1 0 1 0 1 0.55625 AA 1 0 1 0 1 0 0.55000 AB 1 0 1 0 1 0 0.55000 AC 1 0 1 0 1 1 0.54375 AC 1 0 1 0 1 1 0 0.53750 AD 1 0 1 0 1 1 0 1 0.53125 AE 1 0 1 0 1 1 0 0.52500 AF 1 0 1 0 1 1 1 0.51875 BO 1 0 1 1 0 0 0 0.51250 BI 1 0 1 1 0 0 0 0.51250 B2 1 0 1 1 0 0	A7	1	0	1	0	0	1	1	1	0.56875	
AA 1 0 1 0 1 0 1 0 1 0 0.55000 AB 1 0 1 0 1 0 1 0 1 1 0 0.54375 AC 1 0 1 0 1 1 0 0 0 0.53750 AD 1 0 1 0 1 1 0 1 0 0 0.53125 AE 1 0 1 0 1 0 1 1 1 0 0.52500 AF 1 0 1 0 1 1 1 1 1 0 0.51875 B0 1 0 1 1 1 0 0 0 0 0 0 0.51250 B1 1 0 1 1 0 0 0 0 0 0 0.51250 B2 1 0 1 1 0 0 1 1 0 0 1 0 0 0 0 0 0.50000 B3 1 0 1 1 0 0 1 1 0 0 1 0 0 0 0 0.50000 B3 1 0 1 1 0 0 1 1 0 0 0 1 0 0.50000 B3 1 0 1 1 0 0 1 1 0 0 0 0 0 0.48750 B6 1 0 1 1 0 0 1 1 0 0 0 0 0 0.48750 B7 1 0 1 1 0 0 1 1 1 0 0 0 0 0 0.46875 B8 1 0 1 1 1 1 0 0 0 0 0 0.46250 B9 1 0 1 1 1 1 0 0 0 1 0.45625	A8	1	0	1	0	1	0	0	0	0.56250	
AB 1 0 1 0 1 0 1 0 1 1 0.54375 AC 1 0 1 0 1 0 1 1 0 0 0.53750 AD 1 0 1 0 1 1 0 1 0 0.53125 AE 1 0 1 0 1 1 1 0 0.52500 AF 1 0 1 0 1 1 1 1 1 0 0.51875 B0 1 0 1 1 0 0 1 1 1 1 1 0 0.51250 B1 1 0 1 1 0 0 0 0 0 0 0.51250 B2 1 0 1 1 0 0 1 1 0 0 1 0 0 0 0 0 0.50000 B3 1 0 1 1 0 0 1 1 0 0 1 0 0 0 0 0.50000 B3 1 0 1 1 0 0 0 1 1 0 0.50000 B3 1 0 1 1 0 0 0 1 1 0 0.49375 B4 1 0 1 1 0 0 1 0 0 0 0 0.48750 B5 1 0 1 1 0 1 1 0 1 0 0 0 0.48750 B7 1 0 1 1 0 1 1 0 0 0 0 0 0.46875 B8 1 0 1 1 1 1 0 0 0 0 0 0.46250 B9 1 0 1 1 1 1 0 0 1 0 0 0.45625	A9	1	0	1	0	1	0	0	1	0.55625	
AC 1 0 1 0 1 0 0 0.53750 AD 1 0 1 0 1 0 1 0.53125 AE 1 0 1 0 1 1 0 0.52500 AF 1 0 1 0 1 1 1 0.51875 BO 1 0 1 1 1 1 1 0.51875 BO 1 0 1 1 0 0 0 0.51250 B1 1 0 1 1 0 0 0 0.51250 B2 1 0 1 1 0 0 0 1 0.50625 B2 1 0 1 1 0 0 1 0.50000 B3 1 0 1 1 0 0 1 0.49375 B4 1	AA	1	0	1	0	1	0	1	0	0.55000	
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AD 1 0 1 0 1 0 1 1 0 1 0.53125 AE 1 0 1 0 1 1 1 1 0 0.52500 AF 1 0 1 0 1 1 1 1 1 0 0.51875 BO 1 0 1 1 0 0 0 0 0 0 0.51250 B1 1 0 1 1 0 0 0 0 1 0.50625 B2 1 0 1 1 0 0 1 1 0 0 0 1 0.50625 B2 1 0 1 1 0 0 1 1 0 0 0 1 0.50000 B3 1 0 1 1 0 0 0 1 1 0 0.50000 B3 1 0 1 1 0 0 0 1 1 0 0.49375 B4 1 0 1 1 0 0 1 0 0 0.48750 B5 1 0 1 1 0 1 1 0 1 0 0 0.47500 B7 1 0 1 1 0 0 1 1 1 0 0 0 0.46875 B8 1 0 1 1 1 1 0 0 0 0 0.46250 B9 1 0 1 1 1 1 0 0 1 0.45625		1	0	1		1	1	0	0		
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B3 1 0 1 1 0 0 1 1 0.49375 B4 1 0 1 1 0 1 0 0 0.48750 B5 1 0 1 1 0 1 0 1 0.48125 B6 1 0 1 1 0 0 0.47500 B7 1 0 1 1 0 1 1 0.46875 B8 1 0 1 1 1 0 0 0.46250 B9 1 0 1 1 1 0 0 1 0.45625											
B4 1 0 1 1 0 1 0 0 0.48750 B5 1 0 1 1 0 1 0 1 0.48125 B6 1 0 1 1 0 1 1 0 0.47500 B7 1 0 1 1 1 1 0 0.46875 B8 1 0 1 1 1 0 0 0 0.46250 B9 1 0 1 1 1 0 0 1 0.45625											
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B6 1 0 1 1 0 0.47500 B7 1 0 1 1 0 0.46875 B8 1 0 1 1 0 0 0.46250 B9 1 0 1 1 1 0 0 1 0.45625											
B7 1 0 1 1 0 1 1 1 0.46875 B8 1 0 1 1 1 0 0 0 0.46250 B9 1 0 1 1 1 0 0 1 0.45625	B5	1	0	1	1	0	1	0	1		
B8 1 0 1 1 1 0 0 0 0 0.46250 B9 1 0 1 1 1 0 0 1 0.45625	B6	1	0	1	1	0	1	1	0	0.47500	
B9 1 0 1 1 1 0 0 1 0.45625	B7	1	0	1	1	0	1	1	1	0.46875	
	B8	1	0	1	1	1	0	0	0	0.46250	
BA 1 0 1 1 1 0 1 0 0.45000	B9	1	0	1	1	1	0	0	1	0.45625	
	ВА	1	0	1	1	1	0	1	0	0.45000	



Table 5. VID Table (continued)

VID VDAC Hex 0.44375 ВВ BC 0.43750 BD 0.43125 ΒE 0.42500 BF 0.41875 C0 0.41250 C1 0.40625 C2 0.40000 СЗ 0.39375 C4 0.38750 C5 0.38125 C6 0.37500 C7 0.36875 C8 0.36250 C9 0.35625 CA 0.35000 СВ 0.34375 СС 0.33750 CD 0.33125 CE 0.32500 CF 0.31875 D0 0.31250 D1 0.30625 D2 0.30000 0.29375(1) $0.28750^{(1)}$ D5 0.28125(1) D6 $0.27500^{(1)}$ D7 $0.26875^{(1)}$ 0.26250(1) D9 $0.25625^{(1)}$ DA $0.25000^{(1)}$ DB $0.24375^{(1)}$ $0.23750^{(1)}$ DD $0.23125^{(1)}$ $0.22500^{(1)}$ DF $0.21875^{(1)}$

Table 5. VID Table (continued)

						•			
VID									VDAC
Hex	7	6	5	4	3	2	1	0	VDAG
E0	1	1	1	0	0	0	0	0	0.21250 ⁽¹⁾
E1	1	1	1	0	0	0	0	1	0.20625(1)
E2	1	1	1	0	0	0	1	0	0.20000(1)
E3	1	1	1	0	0	0	1	1	0.19375(1)
E4	1	1	1	0	0	1	0	0	0.18750 ⁽¹⁾
E5	1	1	1	0	0	1	0	1	0.18125 ⁽¹⁾
E6	1	1	1	0	0	1	1	0	0.17500 ⁽¹⁾
E7	1	1	1	0	0	1	1	1	0.16875(1)
E8	1	1	1	0	1	0	0	0	0.16250 ⁽¹⁾
E9	1	1	1	0	1	0	0	1	0.15625(1)
EA	1	1	1	0	1	0	1	0	0.15000 ⁽¹⁾
EB	1	1	1	0	1	0	1	1	0.14375 ⁽¹⁾
EC	1	1	1	0	1	1	0	0	0.13750(1)
ED	1	1	1	0	1	1	0	1	0.13125(1)
EE	1	1	1	0	1	1	1	0	0.12500(1)
EF	1	1	1	0	1	1	1	1	0.11875 ⁽¹⁾
F0	1	1	1	1	0	0	0	0	0.11250 ⁽¹⁾
F1	1	1	1	1	0	0	0	1	0.10625(1)
F2	1	1	1	1	0	0	1	0	0.10000(1)
F3	1	1	1	1	0	0	1	1	0.09375(1)
F4	1	1	1	1	0	1	0	0	0.08750 ⁽¹⁾
F5	1	1	1	1	0	1	0	1	0.08125(1)
F6	1	1	1	1	0	1	1	0	0.07500(1)
F7	1	1	1	1	0	1	1	1	0.06875(1)
F8	1	1	1	1	1	0	0	0	0.06250(1)
F9	1	1	1	1	1	0	0	1	0.05625(1)
FA	1	1	1	1	1	0	1	0	0.05000(1)
FB	1	1	1	1	1	0	1	1	0.04375(1)
FC	1	1	1	1	1	1	0	0	0.03750(1)
FD	1	1	1	1	1	1	0	1	0.03125(1)
FE	1	1	1	1	1	1	1	0	OFF
FF	1	1	1	1	1	1	1	1	OFF

⁽¹⁾ Device operating characteristics and tolerances below 0.3 V are not specified.

APPLICATION INFORMATION

Design Procedure

The TPS53624 has the simplest design procedure of any IMVP6.5 CORE controller on the market.

Choosing Initial Parameters

Step One

Determine the processor specifications. For the purposes of this document, the Intel® Auburndale 45-V Processor from Table 2 of the RS – Intel® IMVP-6.5 Mobile Processor and Mobile Chipset Voltage Regulation Specification, Reference Number 24779, Revision 1.0 is used.

The processor requirements provide the following key parameters.

- V_{HFM} = 1.075 V
- $R_{IMVP} = -1.9 \text{ m}\Omega$
- I_{CC(max)} = 50 A
- I_{DYN(max)} = 35 A
- I_{CC(tdc)} = 37 A
- Slew rate = 5 mV/µs (minimum)

The last requirement shows that the converter must support a 25% overcurrent for 10 µs without going out of tolerance. The TPS53624 is designed to support the momentary OCP requirement internally, so only the DC OCP limit needs to be considered when calculating OCP levels. This also means that the power-chain does not have to be over-designed to meet Intel requirements.

Step Two

Determine system parameters.

The input voltage range and operating frequency are of primary interest.

For example

- V_{IN(max)} = 20 V
- V_{IN(min)} = 9 V
- f_{SW} = 300 kHz

Step Three

Determine current sensing method.

The TPS53624 supports both resistor sensing and inductor DCR sensing. Inductor DCR sensing is chosen.

For resistor sensing, substitute the resistor value (1 m Ω recommended for a 50-A application) for R_{CS} in the subsequent equations and skip Step Five.



Step Four

Determine inductor value and choose inductor.

Smaller inductor values have better transient performance but higher ripple and lower efficiency. Higher values have the opposite characteristics. It is common practice to limit the ripple current to between 30% and 50% of the maximum current per phase. In this case, use 40%:

$$I_{P-P} = \frac{50 \,\text{A}}{2 \text{phases}} \times 0.4 = 10 \,\text{A} \tag{7}$$

At f_{SW} = 300 kHz, with a 20-V input and a 1.075-V output.

$$L = \frac{V \times dT}{I_{P-P}}$$

where

$$V = \left(V_{IN(max)} - V_{HFM}\right)$$

$$dT = \left(\frac{V_{HFM}}{\left(f \times V_{IN(max)}\right)}\right)$$
(8)

L=0.34 µH

An inductance value of $0.36~\mu H$ is chosen. Ensure that the inductor does not saturate during peak loading conditions.

$$I_{SAT} = \left(\frac{I_{CC(max)}}{N_{PHASE}} + \frac{I_{P-P}}{2}\right) \times 1.2 \times 1.25 = 45 \text{ A}$$
(9)

The factor of 1.2 is included to allow for current sensing and current limiting tolerances. The factor of 1.25 is due to Intel's 25% momentary OCP requirement described above.

The chosen inductor should have the following characteristics:

- As flat an inductance vs. current curve as possible. Inductor DCR sensing is based on the idea L/DCR is approximately a constant through the current range of interest.
- Either high saturation or soft saturation
- Low DCR for improved efficiency, but at least 0.7 mΩ for proper signal levels.
- DCR tolerance as low as possible for load-line accuracy.

For this application, a 0.36-μH, 1.0-mΩ inductor is chosen.

Step Five

Design the thermal compensation network.

In most designs, NTC thermistors are used to compensate thermal variations in the resistance of the inductor winding. This winding is generally copper, and therefore has a resistance coefficient of 3900 PPM/°C. NTC thermistors, however, have very non-linear characteristics and need two or three resistors to linearize them over the range of interest. The typical DCR circuit is shown in Figure 8.

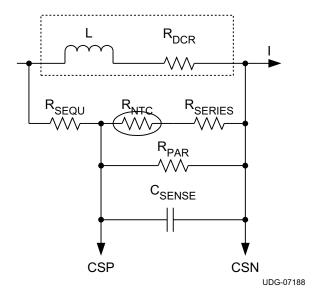


Figure 8. Typical DCR Sensing Circuit

In this circuit, good performance is obtained when:

$$\frac{L}{R_{DCR}} = C_{SENSE} \times R_{EQ} \tag{10}$$

In Equation 10, all of the parameters are defined in Figure 8 except R_{EQ} , which is the series/parallel combination of the other four discrete resistors. C_{SENSE} should be a capacitor type which is stable over temperature. Use X7R or better dielectric (C0G preferred).

Because calculating these values by hand is difficult, TI offers a spreadsheet using the Excel *Solver* function. Contact your local TI representative to get a copy of the spreadsheet.

In the reference design, the following values are input to the spreadsheet:

- L = 0.36 µH
- $R_{DCR} = 1 \text{ m}\Omega$
- Load Line (typically -1.9 mΩ for SV processors)
- Minimum overcurrent limit = 56 A
- Thermistor R₂₅ and "B" value = 4700 kΩ

The spreadsheet then calculates the TRIPSEL setting and the values of:

- R_{SEQU}
- R_{SERIES}
- R_{PAR}
- C_{SENSE}

In this case, the TRIPSEL setting is TRIPSEL = 5 V with R_{SLEW} to GND and the nearest standard component values are:

- $R_{SERIES} = 43.2 \text{ k}\Omega$
- R_{PAR} = 143 kΩ
- $R_{SEQU} = 24.3 \text{ k}\Omega$
- C_{SENSE} = 18 nF



Note the effective divider ratio for the inductor DCR. The effective current sense resistance ($R_{CS(eff)}$) is shown in Equation 11.

$$R_{CS(eff)} = R_{DCR} \times \frac{R_{P_N}}{R_{SEQU} + R_{P_N}}$$

where

• $R_{P N}$ is the series/parallel combination of $R_{NTC}R_{SERIES}$ and R_{PAR} (11)

$$R_{P-N} = \frac{R_{PAR} \times (R_{NTC} + R_{SERIES})}{R_{PAR} + R_{NTC} + R_{SERIES}}$$
(12)

 $R_{CS(eff)}$ is 0.77 m Ω .

Step Six

Determine the output capacitor configuration.

Intel has several recommended configurations in the specifications. The TPS53624 meets every requirement with margin using the minimum configuration given in the Intel specification (Option 3). Depending on the layout, it is possible to reduce the output capacitance further, or to use alternate capacitor technologies. A good rule of thumb is that a successful design has a combination of bulk and ceramic capacitance totaling at least 1600 µF.

Step Seven

Set the load line.

The load line is set by the droop resistor using R_{IMVP} and R_{CS(eff)}

$$R_{DROOP} = \frac{R_{CS(eff)} \times A_{CS}}{G_{M} \times R_{IMVP}} = 4.75 \text{k}\Omega$$
(13)

Step Eight

Calculate the droop capacitor value.

$$C_{DROOP} = \frac{R_{LL} \times \Delta I_{OUT} \times g_{M} \times L}{R_{CS} \times A_{CS} \times D_{MAX} \times V(L)} - 30 \, pF = 105 \, pF$$
(14)

Because better overall transient performance is obtained by allowing a small ring-back, a small value capacitor (between 33 pF and 68 pF) is used. This capacitor also helps in eliminating any noise that may be present at the DROOP pin.

Step Nine

Calculate RSI FW.

 R_{SLEW} sets the slew rate and the soft-start rate. The soft-start rate is 1/8 of the slew rate. Given the Intel requirements, the slew rate minimum requirement is 5 mV/ μ s.

$$R_{SLEW} = \frac{K_{SLEW} \times V_{SLEW}}{SR}$$

here

From the overcurrent limit setting in Step Five, R_{SLEW} is terminated to GND

•
$$K_{SLEW} = 1.25 \times 10^9$$

• $V_{SLEW} = 1.25 \text{ V}$ (15)

Taking into account the tolerance on K_{SLEW} , $R_{SLEW} = 250 \text{ k}\Omega$.

(16)

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Step Ten

Calculate R_{IMON}.

R_{IMON} is calculated to set the voltage on the IMON pin to approximately 1.0 V at maximum processor current.

$$R_{IMON} = \frac{V_{IMON}}{K_{IMON} \times I_{CC(max)} \times R_{CS(eff)}} \left(\Omega\right)$$

here

- V_{IMON} = 1.0 V
- $K_{IMON} = 2 \mu A/mV$
- I_{CC(max)} = 50 A
- $R_{CS(eff)} = 0.77 \text{ m}\Omega$
- $R_{IMON} = 13.1 \text{ k}\Omega$
- C_{IMON} = 3300pF and is added in parallel to R_{IMON} to give a smooth response on IMON pin.

Step Eleven

Calculate THAL pin components.

The THERM pin produces a nominal 61 μ A current. The trip voltage is 0.75 V. Therefore, the resistance at the trip point needs to be 0.75V / 61 μ A = 12.3 k Ω . For a trip temperature of 85°C, the recommended 150 k Ω NTC thermistor is 10.3 k Ω . To move the trip point to the correct resistance, we add a series resistance of 2.0 k Ω . Depending on the thermistors selection and desired trip point, adding a parallel resistance to obtain the correct resistance at the trip point is also possible. In order to keep the sensing as accurate as possible in both cases, the contribution of the fixed resistance at the trip point should be as small as possible.

- V5IN decoupling ≥ 2.2 µF, ≥ 10 V
- V5FILT decoupling ≥ 1 μF, ≥ 10 V
- VREF decoupling 0.22 µF to 1 µF, ≥ 4 V
- Bootstrap capacitors ≥ 0.22 μF, ≥ 10 V Bootstrap diodes (optional) 30 V Schottky diode, BAT-54 or better
- Pull-up resistors on PGOOD. PG. THAL, and PCNT pins per Intel guidelines

For power chain and other component selection, see Table 2.

Step Twelve

Select decoupling and peripheral components.

For peripheral capacitors use the following minimum values of ceramic capacitance. A capacitor with an X5R or better temperature coefficient is recommended. Tighter tolerances and higher voltage ratings are always appropriate.

- V5IN decoupling ≥ 2.2 µF, ≥ 10V
- V5FILT decoupling ≥ 1 µF, ≥ 10V
- VREF decoupling 0.22 µF to 1 µF, ≥ 4 V
- Bootstrap capacitors ≥ 0.22 μF, ≥ 10 V
- Bootstrap diodes (optional) 30 V Schottky diode, BAT-54 or better
- Pull-up resistors on PGOOD, PG, THAL, and PCNT pins per Intel guidelines



Layout Guidelines

The TPS53624 has fully differential current and voltage feedback. As a result, no special layout considerations are required. However, all high-performance multi-phase power converters, like the TPS53624, require a certain level of care in layout.

Schematic Review

Because the voltage and current feedback signals are fully differential it is a good idea to double check the polarity.

- CSP1 / CSN1
- CSP2 / CSN2
- VCCSENSE to VFB / VSSSENSE to GSNS

Specific Guidelines

Separate Noisy Driver Interface Lines from Sensitive Analog Interface Lines

The TPS53624 makes this as easy as possible, as the two sets of pins are on opposite sides of the device. In addition, the CPU interface signals are grouped on one side of the device, and the MCH and platform interface signals are grouped on the opposite side. This arrangement is shown in Figure 9.

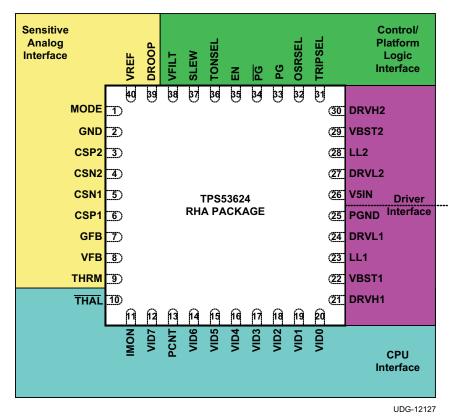


Figure 9. Device Layout by Pin Function

Given the physical layout of most systems, the current feedback (CSPx, CSNx) may have to pass near the power chain. Clean current feedback is required for good load-line, current sharing, and current limiting performance of the TPS53624. This requires the designer take the following precautions.

- Make a Kelvin connection to the pads of the resistor or inductor used for current sensing. See Figure 10 for a layout example.
- Lay out the current feedback signals as a differential pair to the device.
- Lay out the lines in a quiet layer. Isolate them from noisy signals by a voltage or ground plane.



- Design the compensation capacitor for DCR sensing (C_{SENSE}) as close to the CS pins as possible.
- Place R_{PAR} near C_{SENSE}.
- Place any noise filtering capacitors directly under the TPS53624 and connect to the CS pins with the shortest trace length possible.

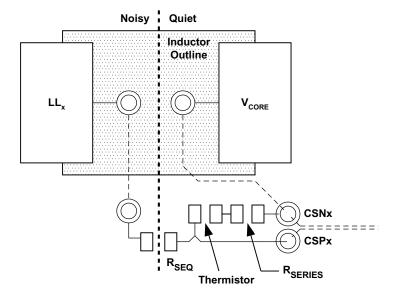


Figure 10. Make Kelvin Connections to the Inductor for DCR Sensing

UDG-07189

- Ensure that all vias in the CSPx and CSNx traces are isolated from all other signals
- Lay out the dotted signal traces in internal planes
- If possible, change the name of the CSNx trace to prevent unintended connections to the V_{CORE} plane
- · Design CSPx and CSNx as a differential pair in a quiet layer
- Design the capacittor as near to the device pins as possible



Minimize High Current Loops

Figure 11 shows the primary current loops in each phase, numbered in order of importance. The most important loop to minimize the area of is Loop 1, the path from the input capacitor through the high and low-side MOSFETs, and back to the capacitor through ground.

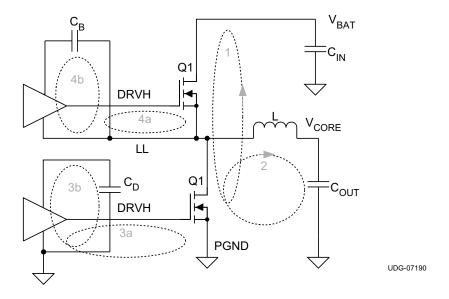


Figure 11. Major Current Loops Requiring Minimization

Loop 2 is from the inductor through the output capacitor, ground and Q2. The layout of the low-side gate drive (Loops 3a and 3b) is important. The guidelines for gate drive layout are:

- Make the low side gate drive as short as possible (1 inch or less preferred).
- Make the DRVL width to length ratio of 1:10, wider (1:5) if possible
- · If changing layers is necessary, use at least two vias



Power Chain Symmetry

The TPS53624 does not require special care in the layout of the power chain components, because independent isolated current feedback is provided. Make every effort to lay out the phases in a symmetrical manner. The current feedback from each phase must be free of noise and have the same effective current sense resistance. A value of 1 m Ω of current feedback resistance is recommended.

Place Analog Components as Close to the Device as Possible

Place components close to the device in the following order.

- 1. CS pin noise filtering components
- 2. DROOP pin compensation component
- 3. Decoupling capacitor
- 4. SLEW resistor (R_{SLEW})

Grounding Recommendations

The TPS53624 has separate analog and power grounds, and a thermal pad. The normal procedure for connecting these is:

- 1. Connect the thermal pad to PGND.
- 2. Tie the thermal pad to the system ground plane with at least 4 small vias or one large via.
- 3. GND can be connected to any quiet space. A quiet space is defined as a spot where no power supply switching currents are likely to flow. This applies to both the VCORE regulator and other regulators. Use a single point connection to the point, and pour a GND island around the analog components.
- 4. Make sure the low-side MOSFET source connection and the decoupling capacitors have plenty of vias.

Decoupling Recommendations

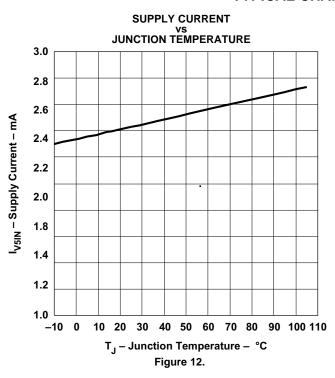
- Decouple V5 to PGND with at least a 2.2-µF ceramic capacitor. This fits best on the opposite side of the
 device.
- · Use double vias to connect to the device.
- Decouple V5FILT with 1-µF to AGND with leads as short as possible.
- Decouple VREF to AGND with 0.22-µF, with short leads as short as possible.

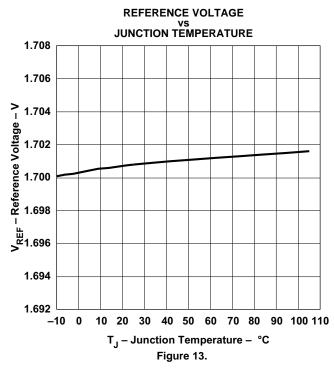
Conductor Widths

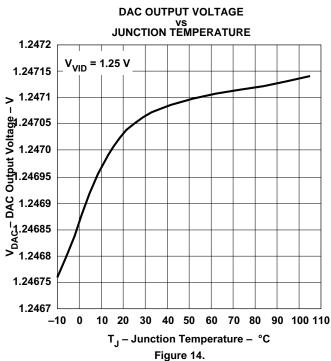
- Follow Intel guidelines with respect to the voltage feedback and logic interface connection requirements.
- Maximize the widths of power, ground and drive signal connections.
- For conductors in the power path, be sure there is adequate trace width for the amount of current flowing through the traces.
- Make sure there are sufficient vias for connections between layers.
- Use a minimum of 1 via per ampere of current

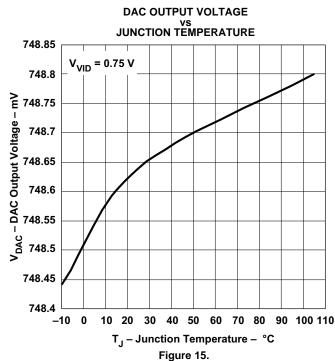


TYPICAL CHARACTERISTICS

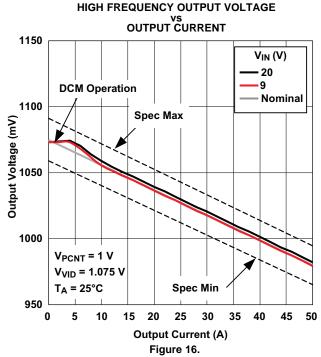


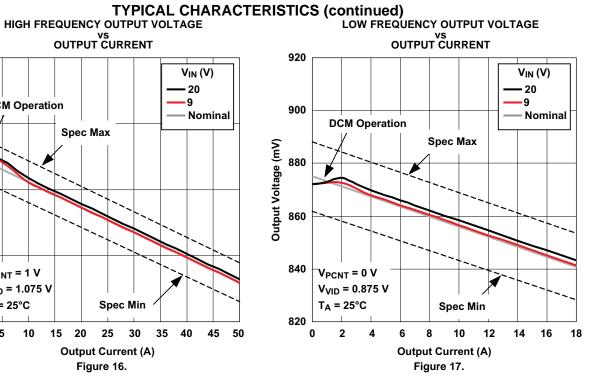




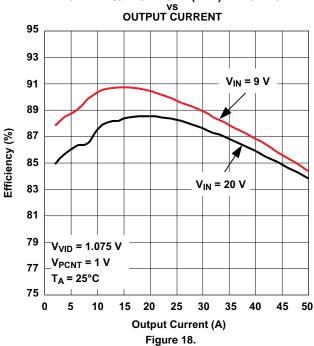


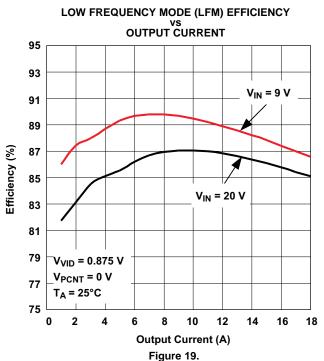






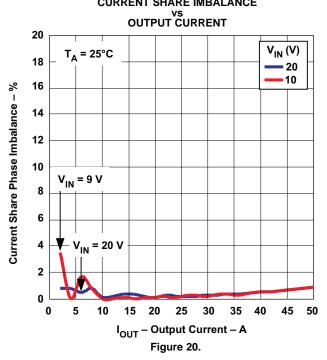
HIGH FREQUENCY MODE (HFM) EFFICIENCY

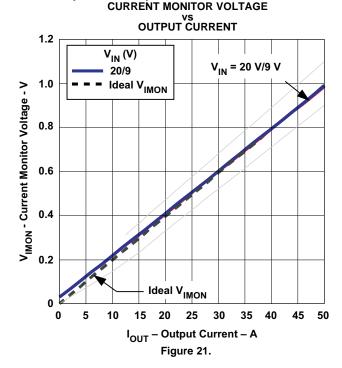


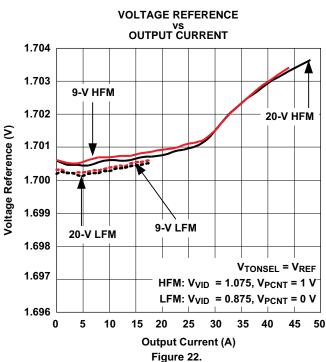


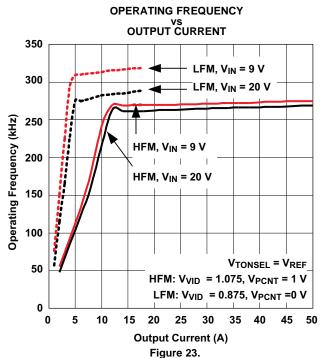






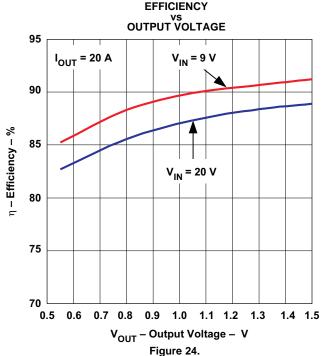


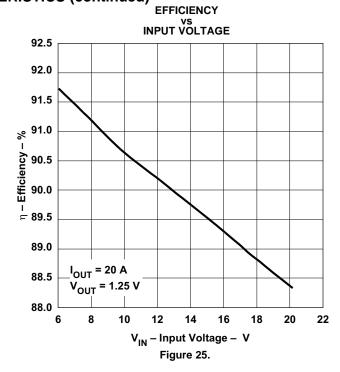












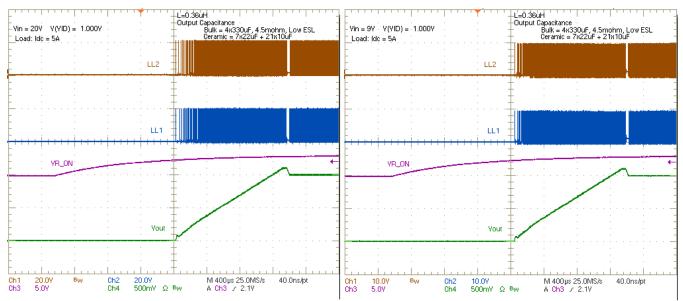


Figure 26. Start-Up, V_{IN} = 20 V

Figure 27. Start-Up, $V_{IN} = 9 V$



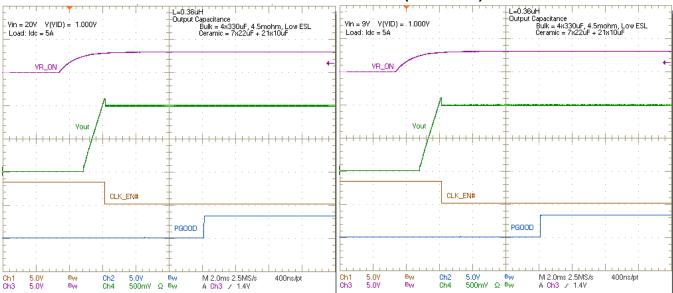


Figure 28. \overline{PG} and PGOOD, V_{IN} = 20 V

Figure 29. \overline{PG} and PGOOD, $V_{IN} = 9 \text{ V}$

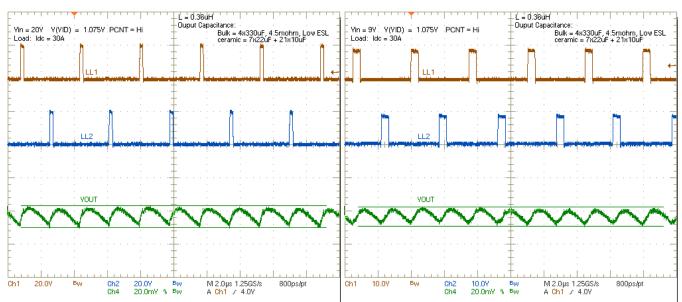


Figure 30. Output Ripple, $V_{IN} = 20 \text{ V}$

Figure 31. Output Ripple, $V_{IN} = 9 V$



TYPICAL CHARACTERISTICS (continued)

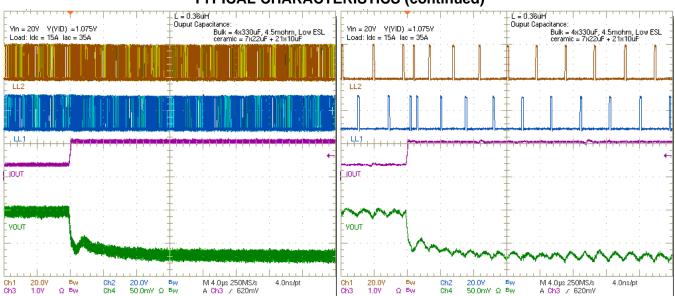


Figure 32. Load Insertion, $V_{\rm IN}$ = 20 V, $I_{\rm DC}$ = 15 A, $I_{\rm AC}$ = 35 A, Persistence Mode

Figure 33. Load Insertion, V_{IN} = 20 V, I_{DC} = 15 A, I_{AC} = 35 A

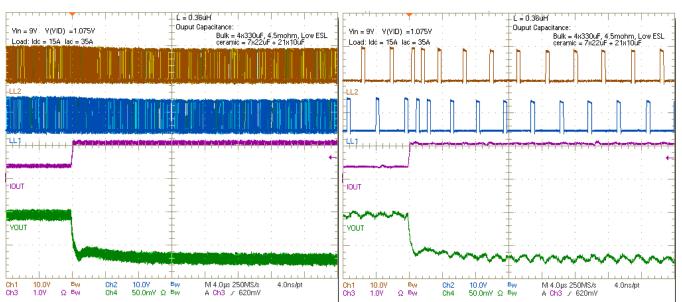


Figure 34. Load Insertion, $V_{\rm IN}$ = 9 V, $I_{\rm DC}$ = 15 A, $I_{\rm AC}$ = 35 A, Persistence Mode

Figure 35. Load Insertion, $V_{\rm IN}$ = 9 V, $I_{\rm DC}$ = 15 A, $I_{\rm AC}$ = 35 A



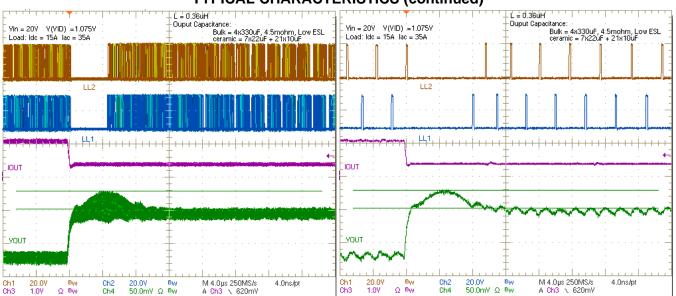


Figure 36. Load Release, $V_{\rm IN}$ = 20 V, $I_{\rm DC}$ = 15 A, $I_{\rm AC}$ = 35 A, Persistence Mode

Figure 37. Load Release, V_{IN} = 20 V, I_{DC} = 15 A, I_{AC} = 35 A

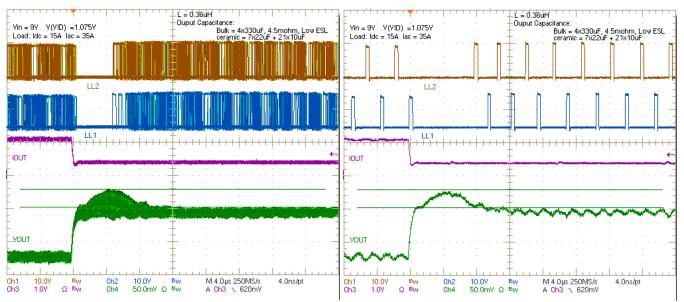


Figure 38. Load Release, V_{IN} = 9 V, I_{DC} = 15 A, I_{AC} = 35 A, Persistence Mode

Figure 39. Load Release, $V_{IN} = 9 V$, $I_{DC} = 15 A$, $I_{AC} = 35 A$,



TYPICAL CHARACTERISTICS (continued)

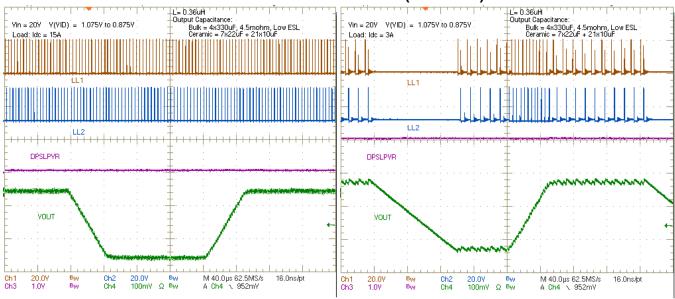


Figure 40. VID Change from 1.075 V to 0.875 V, I_{DC} = 15 A

Figure 41. VID Change from 1.075 V to 0.875 V, I_{DC} = 3 A

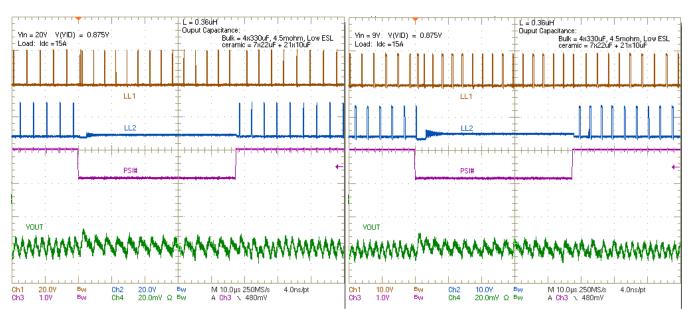
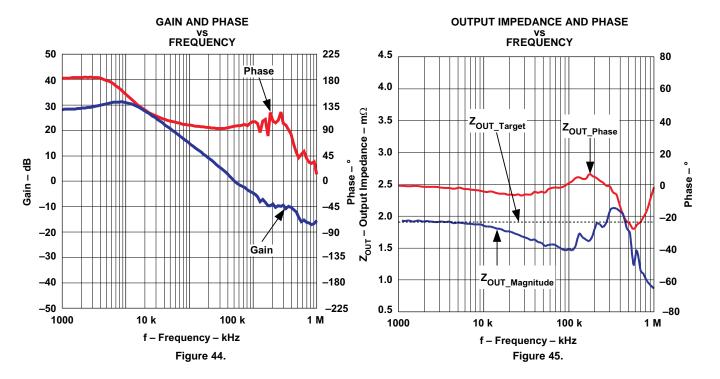


Figure 42. PCNT Toggle: V_{IN} = 20 V

Figure 43. PCNT Toggle: V_{IN} = 9 V





In Figure 44 and Figure 45

- Output bulk capacitance = 4 x 330 μF, 4.5 mΩ, Low ESL
- Output MLCC capacitance = 7 x 22 μF + 21 x 10 μF
- V_{IN} = 20 V
- V_{VID} = 1.075 V

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TPS53624RHAR	Active	Production	VQFN (RHA) 40	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	TPS 53624
TPS53624RHAR.A	Active	Production	VQFN (RHA) 40	2500 LARGE T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	TPS 53624
TPS53624RHAT	Active	Production	VQFN (RHA) 40	250 SMALL T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	TPS 53624
TPS53624RHAT.A	Active	Production	VQFN (RHA) 40	250 SMALL T&R	Yes	NIPDAU	Level-3-260C-168 HR	-40 to 125	TPS 53624

⁽¹⁾ Status: For more details on status, see our product life cycle.

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- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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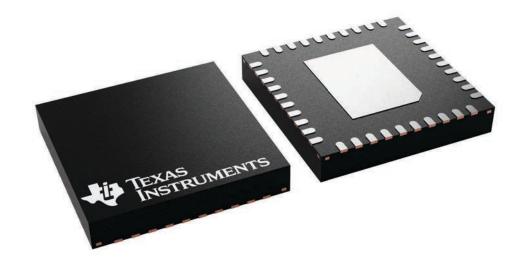
PACKAGE OPTION ADDENDUM

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6 x 6, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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最后更新日期: 2025 年 10 月